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ON Semiconductor MAC16HCDG

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# MAC16HCDG, MAC16HCMG, MAC16HCNG

# **Triacs**

# **Silicon Bidirectional Thyristors**

Designed primarily for full-wave ac control applications, such as motor controls, heating controls or dimmers; or wherever full-wave, silicon gate-controlled devices are needed.

#### **Features**

- High Commutating di/dt and High Immunity to dv/dt @ 125°C
- Uniform Gate Trigger Currents in Three Quadrants, Q1, Q2, and Q3
- Blocking Voltage to 800 Volts
- On–State Current Rating of 16 Amperes RMS at 80°C
- High Surge Current Capability 150 Amperes
- Industry Standard TO-220 Package for Ease of Design
- Glass Passivated Junctions for Reliability and Uniformity
- These Devices are Pb-Free and are RoHS Compliant\*

#### MAXIMUM RATINGS (T<sub>.I</sub> = 25°C unless otherwise noted)

| Rating  | Symbol               | Value             | Unit               |
|---|----------------------|-------------------|--------------------|
| Peak Repetitive Off–State Voltage (Note 1) (T <sub>J</sub> = –40 to 125°C, Sine Wave, 50 to 60 Hz, Gate Open) | $V_{DRM,} \ V_{RRM}$ |                   | V                  |
| MAC16HCD<br>MAC16HCM<br>MAC16HCN  |                      | 400<br>600<br>800 |                    |
| On–State RMS Current<br>(Full Cycle Sine Wave 50 to 60 Hz;<br>T <sub>C</sub> = 80°C)                          | I <sub>T(RMS)</sub>  | 16                | A                  |
| Peak Non-Repetitive Surge Current (One Full Cycle, 60 Hz, T <sub>J</sub> = 125°C)                             | I <sub>TSM</sub>     | 150               | Α                  |
| Circuit Fusing Consideration (t = 8.33 ms)  | l <sup>2</sup> t     | 93                | A <sup>2</sup> sec |
| Peak Gate Power<br>(Pulse Width ≤ 1.0 μs, T <sub>C</sub> = 80°C)  | P <sub>GM</sub>      | 20                | W                  |
| Average Gate Power<br>(t = 8.3 ms, T <sub>C</sub> = 80°C)   | P <sub>G(AV)</sub>   | 0.5               | W                  |
| Operating Junction Temperature Range  | TJ                   | -40 to +125       | °C                 |
| Storage Temperature Range   | T <sub>stg</sub>     | -40 to +150       | °C                 |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

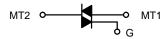
 V<sub>DRM</sub> and V<sub>RRM</sub> for all types can be applied on a continuous basis. Blocking voltages shall not be tested with a constant current source such that the voltage ratings of the devices are exceeded.

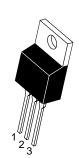


# ON Semiconductor®

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# TRIACS 16 AMPERES RMS 400 thru 800 VOLTS





### MARKING DIAGRAM



TO-220 CASE 221A STYLE 4

= D, M, or N= Assembly Location

Y = Year WW = Work Week G = Pb-Free Package

| PIN ASSIGNMENT |                 |  |  |
|----------------|-----------------|--|--|
| 1              | Main Terminal 1 |  |  |
| 2              | Main Terminal 2 |  |  |
| 3              | Gate            |  |  |
| 4              | Main Terminal 2 |  |  |

#### ORDERING INFORMATION

| Device    | Package             | Shipping        |
|-----------|---------------------|-----------------|
| MAC16HCDG | TO-220<br>(Pb-Free) | 50 Units / Rail |
| MAC16HCMG | TO-220<br>(Pb-Free) | 50 Units / Rail |
| MAC16HCNG | TO-220<br>(Pb-Free) | 50 Units / Rail |

<sup>\*</sup>For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



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# MAC16HCDG, MAC16HCMG, MAC16HCNG

#### THERMAL CHARACTERISTICS

| Characteristic  | Symbol                        | Value       | Unit |
|---|-------------------------------|-------------|------|
| Thermal Resistance, Junction-to-Case Junction-to-Ambient                      | $R_{	heta JC} \ R_{	heta JA}$ | 2.2<br>62.5 | °C/W |
| Maximum Lead Temperature for Soldering Purposes 1/8" from Case for 10 Seconds | TL                            | 260         | °C   |

# **ELECTRICAL CHARACTERISTICS** (T = 25°C unless otherwise noted: Flectricals apply in both directions)

| Characteristic   | Symbol            | Min               | Тур                  | Max               | Unit |
|--|-------------------|-------------------|----------------------|-------------------|------|
| DFF CHARACTERISTICS  |                   |                   |                      |                   |      |
| Peak Repetitive Blocking Current $T_J = 25^{\circ}C$ $(V_D = Rated V_{DRM}, V_{RRM}, Gate Open)$ $T_J = 125^{\circ}C$  | Bittii            | -<br>-            | _<br>_               | 0.01<br>2.0       | mA   |
| ON CHARACTERISTICS   |                   |                   |                      |                   |      |
| Peak On-State Voltage (Note 2) (I <sub>TM</sub> = ±21 A Peak)  | $V_{TM}$          | -                 | -                    | 1.6               | V    |
| Gate Trigger Current (Continuous dc) ( $V_D$ = 12 V, $R_L$ = 100 $\Omega$ ) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)   | I <sub>GT</sub>   | 10<br>10<br>10    | 16<br>18<br>22       | 50<br>50<br>50    | mA   |
| Holding Current ( $V_D = 12 \text{ V}$ , Gate Open, Initiating Current = $\pm 150 \text{ m/s}$   | N) I <sub>H</sub> | -                 | 20                   | 50                | mA   |
| Latch Current ( $V_D = 12 \text{ V}, I_G = 50 \text{ mA}$ )<br>MT2(+), G(+)<br>MT2(+), G(-)<br>MT2(-), G(-)  | I <sub>L</sub>    | -<br>-<br>-       | 33<br>36<br>33       | 60<br>80<br>60    | mA   |
| Gate Trigger Voltage (Continuous dc) (V <sub>D</sub> = 12 V, R <sub>L</sub> = 100 $\Omega$ ) MT2(+), G(+) MT2(+), G(-) MT2(-), G(-)  | V <sub>GT</sub>   | 0.5<br>0.5<br>0.5 | 0.80<br>0.73<br>0.82 | 1.5<br>1.5<br>1.5 | V    |
| DYNAMIC CHARACTERISTICS  |                   |                   |                      |                   |      |
| Rate of Change of Commutating Current ( $V_D = 400 \text{ V}$ , ITM = 6A, Commutating dv/dt = 20 V/ $\mu$ s, CL = 10 $\mu$ F Gate Open, T $_J = 125^{\circ}$ C, f = 250 Hz, with Snubber) LL = 40 mH | (di/dt)c          | 15                | _                    | _                 | A/ms |
| Critical Rate of Rise of Off–State Voltage (V <sub>D</sub> = Rated V <sub>DRM</sub> , Exponential Waveform, Gate Open, T <sub>J</sub> = 125°C  | dv/dt             | 750               | -                    | -                 | V/μs |
| Repetitive Critical Rate of Rise of On-State Current IPK = 50 A; PW = 40 µsec; diG/dt = 200 mA/µsec; f = 60 Hz   | di/dt             | _                 | -                    | 10                | A/μs |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions. 2. Pulse Test: Pulse Width  $\leq$  2.0 ms, Duty Cycle  $\leq$  2%.

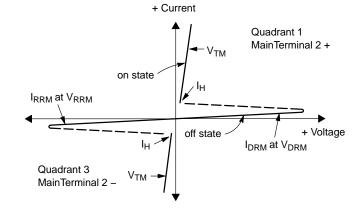
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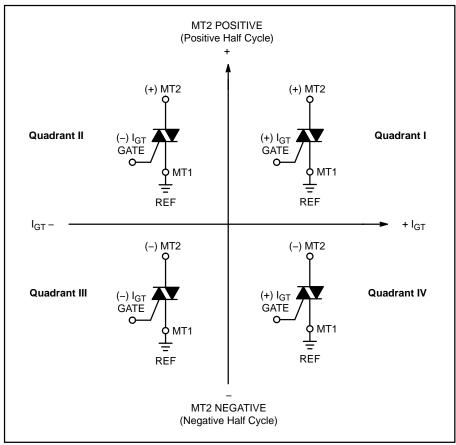
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# Voltage Current Characteristic of Triacs (Bidirectional Device)

| Symbol           | Parameter                                 |
|------------------|---|
| $V_{DRM}$        | Peak Repetitive Forward Off State Voltage |
| I <sub>DRM</sub> | Peak Forward Blocking Current             |
| V <sub>RRM</sub> | Peak Repetitive Reverse Off State Voltage |
| I <sub>RRM</sub> | Peak Reverse Blocking Current             |
| V <sub>TM</sub>  | Maximum On State Voltage                  |
| I <sub>H</sub>   | Holding Current                           |



### **Quadrant Definitions for a Triac**



All polarities are referenced to MT1.

With in-phase signals (using standard AC lines) quadrants I and III are used.

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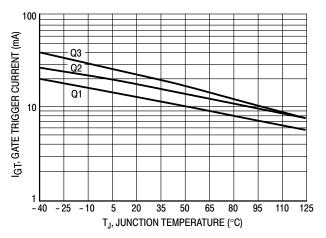


Figure 1. Typical Gate Trigger Current versus Junction Temperature

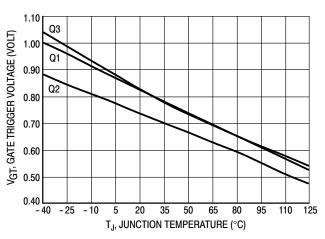


Figure 2. Typical Gate Trigger Voltage versus Junction Temperature

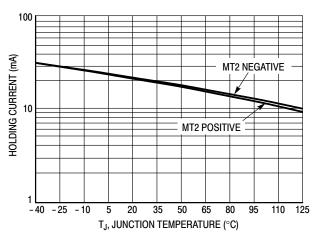


Figure 3. Typical Holding Current versus Junction Temperature

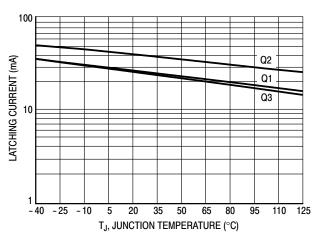


Figure 4. Typical Latching Current versus Junction Temperature

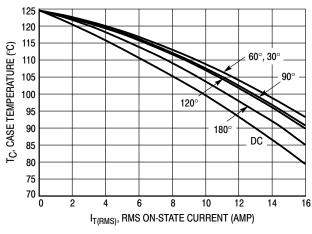


Figure 5. Typical RMS Current Derating

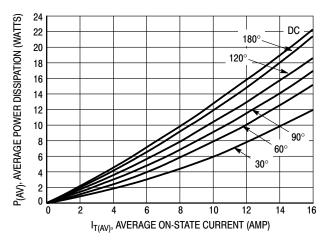
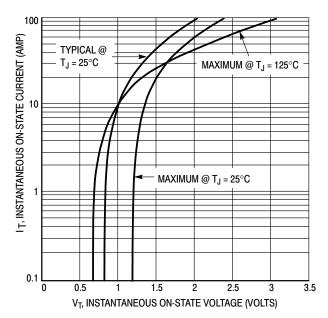


Figure 6. On-State Power Dissipation

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(i) TRANSIENT THERMAL RESISTANCE (NORMALIZED) 0.01 0.1 1 10 100 1000 10000 t, TIME (ms)

Figure 8. Typical Thermal Response

Figure 7. Typical On-State Characteristics



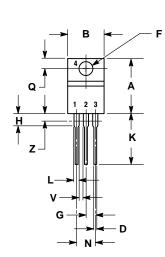
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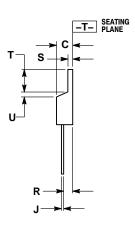
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#### PACKAGE DIMENSIONS

TO-220 CASE 221A-09 **ISSUE AH** 





- NOTES:

  1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.

  2. CONTROLLING DIMENSION: INCH.

  3. DIMENSION Z DEFINES A ZONE WHERE ALL
- BODY AND LEAD IRREGULARITIES ARE

|     | INCHES |       | MILLIMETERS |       |
|-----|--------|-------|-------------|-------|
| DIM | MIN    | MAX   | MIN         | MAX   |
| Α   | 0.570  | 0.620 | 14.48       | 15.75 |
| В   | 0.380  | 0.415 | 9.66        | 10.53 |
| С   | 0.160  | 0.190 | 4.07        | 4.83  |
| D   | 0.025  | 0.038 | 0.64        | 0.96  |
| F   | 0.142  | 0.161 | 3.61        | 4.09  |
| G   | 0.095  | 0.105 | 2.42        | 2.66  |
| Н   | 0.110  | 0.161 | 2.80        | 4.10  |
| J   | 0.014  | 0.024 | 0.36        | 0.61  |
| K   | 0.500  | 0.562 | 12.70       | 14.27 |
| L   | 0.045  | 0.060 | 1.15        | 1.52  |
| N   | 0.190  | 0.210 | 4.83        | 5.33  |
| Q   | 0.100  | 0.120 | 2.54        | 3.04  |
| R   | 0.080  | 0.110 | 2.04        | 2.79  |
| S   | 0.045  | 0.055 | 1.15        | 1.39  |
| T   | 0.235  | 0.255 | 5.97        | 6.47  |
| U   | 0.000  | 0.050 | 0.00        | 1.27  |
| ٧   | 0.045  |       | 1.15        |       |
| Z   |        | 0.080 |             | 2.04  |

#### STYLE 4:

MAIN TERMINAL 1 MAIN TERMINAL 2

MAIN TERMINAL 2

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